

Features :

- Isolated mounting base 3000V~
- Pressure contact technology with Increased power cycling capability
- Space and weight saving

Typical Applications

- Various rectifiers
- DC supply for PWM inverter

V _{RSM}	V _{RRM}	品名
2100V	2000V	Mx1200D200
2300V	2200V	Mx1200D220
2600V	2500V	Mx1200D250

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T _j (°C)	VALUE			UNIT
				Min.	Typ.	Max.	
I _{F(AV)}	Mean forward current	180° half sine wave 50Hz Single side cooled, T _c =100°C	150			1200	A
I _{F(RMS)}	RMS forward current		150			1884	A
I _{RRM}	Repetitive peak current	at V _{RRM}	150			50	mA
I _{FSM}	Surge forward current	10ms half sine wave V _R =0.6V _{RRM}	150			34	kA
I ² t	I ² t for fusing coordination					5780	A ² s*10 ³
V _{FO}	Threshold voltage		150			0.70	V
r _F	Forward slope resistance					0.10	mΩ
V _{FM}	Peak forward voltage	I _{FM} =3000A	25			1.85	V
R _{th(j-c)}	Thermal resistance Junction to case	D.C. Single side cooled per chip				0.042	°C /W
R _{th(c-h)}	Thermal resistance case to heatsink	D.C. Single side cooled per chip				0.020	°C /W
V _{ISO}	Isolation voltage	50Hz, R.M.S, t=1min, I _{ISO} :1mA(max)		3000			V
F _m	Terminal connection torque(M16)				12.0		N·m
	Mounting torque(M6)				6.0		N·m
T _{vj}	Junction temperature			-40		150	°C
T _{stg}	Stored temperature			-40		125	°C
W _t	Weight				3660		g
Outline	M08						

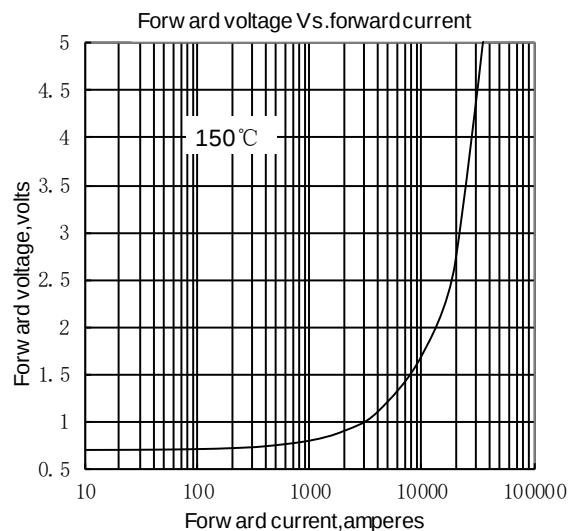


Fig.1

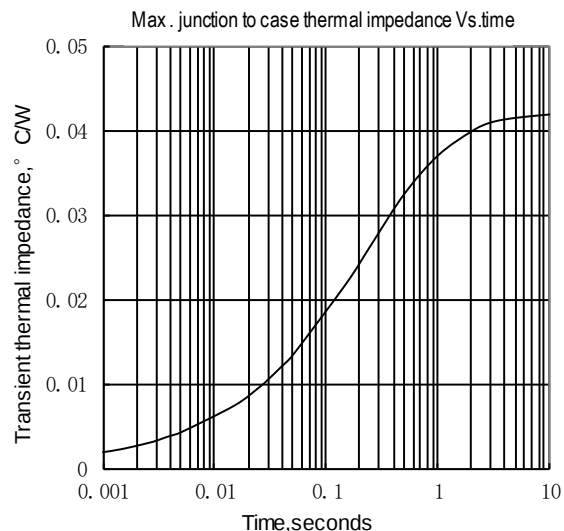


Fig.2

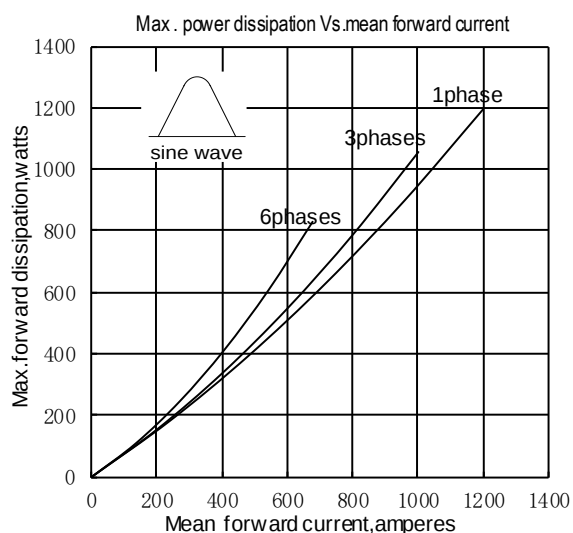


Fig.3

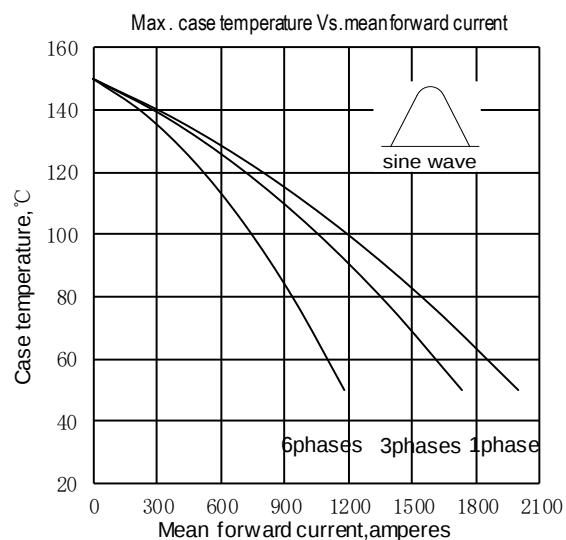


Fig.4

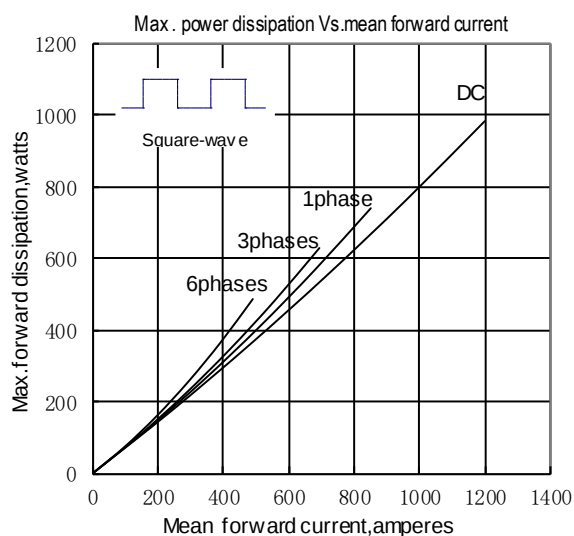


Fig.5

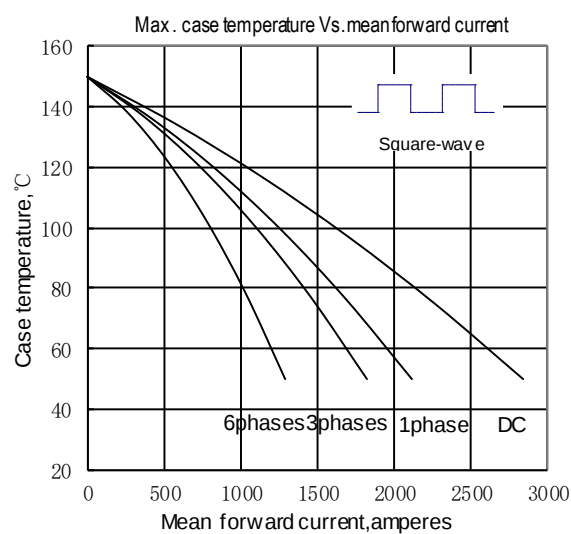


Fig.6

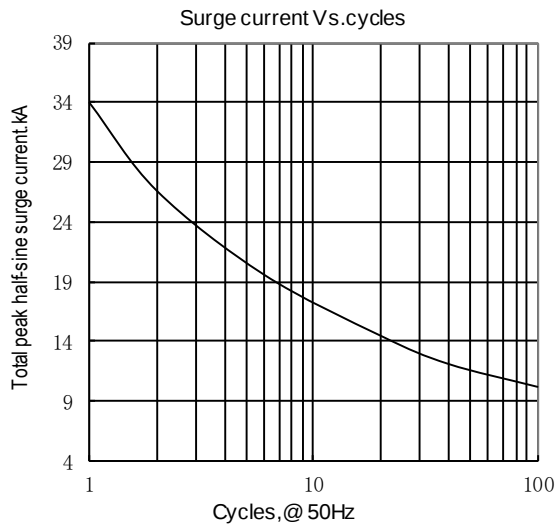
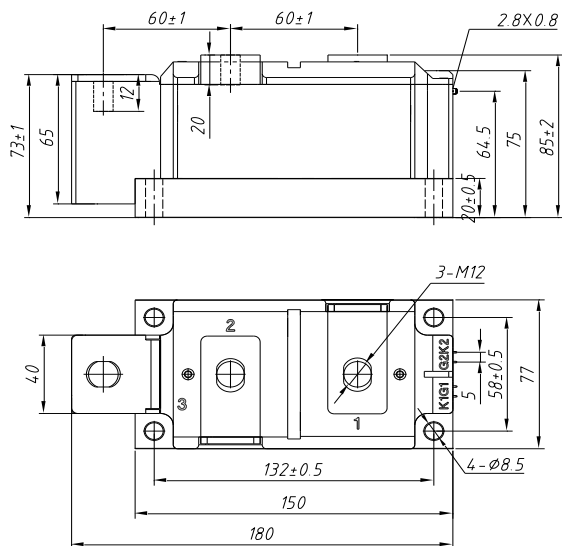
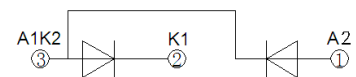


Fig.7

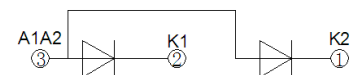


Unmarked dimensional tolerance : ± 0.5 mm

MD1200D**



MR1200D**



MC1200D**

